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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/777,576	02/12/2004	Toshiharu Furukawa	ROC920030271US1	6152
30206	7590 09/11/2007		EXAMINER	
	IBM CORPORATION ROCHESTER IP LAW DEPT. 917 NADAV, ORI			V, ORI
0000	AY 52 NORTH		ART UNIT	PAPER NUMBER
ROCHESTER	, MN 55901-7829		2811	
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			MAIL DATE	DELIVERY MODE
		•	09/11/2007	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No.	Applicant(s)	2	
	10/777,576	FURUKAWA ET AL.	2	
Office Action Summary	Examiner	Art Unit		
	Ori Nadav	2811		
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet w	ith the correspondence address	s	
A SHORTENED STATUTORY PERIOD FOR REPL' WHICHEVER IS LONGER, FROM THE MAILING D. Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. If NO period for reply is specified above, the maximum statutory period v. Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNI 36(a). In no event, however, may a will apply and will expire SIX (6) MOI , cause the application to become A	CATION. reply be timely filed NTHS from the mailing date of this commun BANDONED (35 U.S.C. § 133).		
Status				
1) Responsive to communication(s) filed on 04 Ju	ine 2007.			
2a) ☐ This action is FINAL . 2b) ☑ This	action is non-final.			
3) Since this application is in condition for allowar	nce except for formal mat	ters, prosecution as to the mer	rits is	
closed in accordance with the practice under E	x parte Quayle, 1935 C.E). 11, 453 O.G. 213.		
Disposition of Claims			•	
4) Claim(s) <u>1,3-13,15-20 and 34-53</u> is/are pending	g in the application.			
4a) Of the above claim(s) 9-13,20,36,38-42 and	- ',	rom consideration.		
5) Claim(s) is/are allowed.	•	•		
6) Claim(s) 1,3-8,15-19,34,35,37,43-48,52 and 5	is/are rejected.			
7) Claim(s) is/are objected to.				
8) Claim(s) are subject to restriction and/or	r election requirement.			
Application Papers				
9) The specification is objected to by the Examine	r.	·		
10) The drawing(s) filed on is/are: a) acce	epted or b) objected to	by the Examiner.		
Applicant may not request that any objection to the	drawing(s) be held in abeyar	nce. See 37 CFR 1.85(a).		
Replacement drawing sheet(s) including the correcti	ion is required if the drawing	(s) is objected to. See 37 CFR 1.1	121(d).	
11)☐ The oath or declaration is objected to by the Ex	aminer. Note the attached	d Office Action or form PTO-15	52.	
Priority under 35 U.S.C. § 119				
12) Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. §	119(a)-(d) or (f).		
a) ☐ All b) ☐ Some * c) ☐ None of: 1. ☐ Certified copies of the priority documents	have been received			
= ' ' '		polication No		
 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage 				
application from the International Bureau		received in this National Stage	E	
* See the attached detailed Office action for a list (, , , ,	received		
	or the contined copies not	10001704.		
Attachment(s)				
1) Notice of References Cited (PTO-892)	4) 🔲 Interview S	Summary (PTO-413)		
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s	s)/Mail Date formal Patent Application		
3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	5) Notice of Ir 6) Other:			
S. Patent and Trademark Office PTOL-326 (Rev. 08-06) Office Ac	tion Summary	Part of Paper No /Mail Date 200)70830	

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DETAILED ACTION

In view of the appeal brief filed on 6/04/2007, PROSECUTION IS HEREBY REOPENED. A new rejection is set forth below.

To avoid abandonment of the application, appellant must exercise one of the following two options:

- (1) file a reply under 37 CFR 1.111 (if this Office action is non-final) or a reply under 37 CFR 1.113 (if this Office action is final); or,
 - (2) request reinstatement of the appeal.

If reinstatement of the appeal is requested, such request must be accompanied by a supplemental appeal brief, but no new amendments, affidavits (37 CFR 1.130, 1.131 or 1.132) or other evidence are permitted. See 37 CFR 1.193(b)(2).

Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claim 37 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. The claimed limitation of a catalyst pad, as recited in claim 37, is unclear as to the structural relationship between the claimed circuit and the catalyst pad.

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Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1, 3-8, 15-19, 34-35, 37, 43-48 and 52-53, as best understood, are rejected under 35 U.S.C. 103(a) as being unpatentable over Choi et al. (6,566,704) in view of Ochipinti et al. (2004/0027889).

Regarding claims 1 and 43, Choi et al. teach in figure 3F and related text a circuit comprising:

an interconnected plurality of semiconductor device structures arranged in an array (see figure 2I), each of said semiconductor device structures further comprising a gate electrode 20 including a vertical sidewall and a gate dielectric 30 disposed on the vertical sidewall.

at least one semiconducting carbon nanotube 100 extending substantially vertically between opposite first and second ends at a location adjacent to said vertical sidewall of said gate electrode,

a first contact 40 electrically coupled with said first end of said at least one semiconducting carbon nanotube,

and a second contact 50 electrically coupled with said second end of said at least one semiconducting carbon nanotube.

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Choi et al. do not explicitly state in the embodiment of figure 3F that each of said semiconductor device structures is arranged as an interconnected plurality of semiconductor device structures in an array characterized by a plurality of rows and a plurality of columns.

Choi et al. teach in the embodiment of figure 4B that each of said semiconductor device structures is arranged as an interconnected plurality of semiconductor device structures in an array characterized by a plurality of rows and a plurality of columns.

Ochipinti et al. teach that a memory device conventionally uses an array characterized by a plurality of rows and a plurality of columns (paragraph [0010]).

It would have been obvious to one of ordinary skill in the art at the time the invention was made to use an array characterized by a plurality of rows and a plurality of columns in Choi et al.'s device in order to use the device in a practical application which requires plurality of unit cells and in order to simplify the processing steps of making the device by using conventional rows and columns array matrix.

Regarding claims 3-8, 34, 37, 44-48, Choi et al. teach said at least one semiconducting carbon nanotube is a single-wall semiconducting carbon nanotube, and

a plurality of semiconducting carbon nanotubes extending vertically at a plurality of locations adjacent to said vertical sidewall of said gate electrode (see figure 4B), wherein

said first contact includes a catalyst pad (the first contact is the catalyst pad) characterized by nanocrystals of a catalyst material, wherein

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said first end of said at least one semiconducting carbon nanotube incorporates an electrical-conductivity enhancing substance (the electrical-conductivity enhancing substance is the material of said at least one semiconducting carbon nanotube), and an insulating layer disposed between said first contact and said gate electrode 20 for electrically isolating said first contact from said gate electrode, and

an insulating layer disposed between said second contact and said gate electrode for electrically isolating said second contact from said gate electrode.

Regarding the process limitations recited in claims 5-6, 34, 37 and 46 ("nanocrystals of a catalyst material effective for growing said at least one semiconducting carbon nanotube", and "an electrical-conductivity enhancing substance diffused from said catalyst pad into said first end during growth"), these would not carry patentable weight in this claim drawn to a structure, because distinct structure is not necessarily produced. Note that a "product by process" claim is directed to the product per se, no matter how actually made, In re Hirao, 190 USPQ 15 at 17 (footnote 3). See also In re Brown, 173 USPQ 685; In re Luck, 177 USPQ 523; In re Fessmann, 180 USPQ 324; In re Avery, 186 USPQ 161; In re Wertheim, 191 USPQ 90 (209 USPQ 554 does not deal with this issue); and In re Marosi et al., 218 USPQ 289, all of which make it clear that it is the patentability of the final product per se which must be determined in a "product by process" claim, and not the patentability of the process, and that an old or obvious product produced by a new method is not patentable as a product, whether claimed in

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"product by process" claims or not. Note that the applicant has the burden of proof in such cases, as the above case law makes clear.

Regarding claims 15-18, prior art teach a memory circuit comprising:

a plurality of word lines each electrically intreconnecting said gate electrode of each of said plurality of semiconductor device structurers located in a corresponding one of said plurality of rows of said array; and

a plurality of bit lines each electrically interconnecting said second contact of each of said plurality of semiconductor device structures located in a corresponding one of said plurality of columns of said array, wherein each of said plurality of word lines comprises said gate electrode of each of said plurality of semiconductor device structures located in said corresponding one of said plurality of rows of said array, wherein

each of said plurality of bit lines comprises a conductive stripe electrically coupling said source of each of said plurality of semiconductor device structures located in a corresponding one of said plurality of rows of said array.

Regarding claims 19 and 52, Choi et al. teach in figure 4B and related text a substrate carrying said plurality of semiconductor device structures and characterized by a surface area viewed vertical to the substrate, said plurality of semiconductor device structures separated a space filled by a dielectric material. Prior art do not teach said space ranging from about 20 percent to about 50 percent of said surface area. It would

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have been obvious to one of ordinary skill in the art at the time the invention was made to use a space ranging from about 20 percent to about 50 percent of said surface area in prior art's device in order to reduce the size of the device (by providing a space ranging only from about 20 percent to about 50 percent of the total surface area) and by optimizing the characteristics of the device (by not proving the structures too close to each other which may degrade the device performance).

Regarding claims 35 and 53, prior art teach a capacitor electrically coupled with said first contact.

Claims 5-6, 34, 37 and 46, as best understood, are rejected under 35 U.S.C. 103(a) as being unpatentable over Choi et al. (6,566,704) and Ochipinti et al. (2004/0027889), as applied to claims 1, 35 and 43 above, and further in view of Farnworth et al. (6,515,325).

Regarding claims 5, 34, 37 and 46, Choi et al. and Ochipinti et al. teach substantially the entire claimed structure, as applied to claims 1, 35 and 43 above, except explicitly stating that said first contact includes a catalyst pad characterized by nanocrystals of a catalyst material effective for growing said at least one semiconducting carbon nanotube.

Farnworth et al. teach in figure 2A and related text (column 4, lines 32-50) a first contact includes a catalyst pad (by considering the first contact layer as layer 16, the catalyst

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pad is layer 16) characterized by nanocrystals of a catalyst material effective for growing said at least one semiconducting carbon nanotube.

It would have been obvious to one of ordinary skill in the art at the time the invention was made to form the first contact in prior art's device by including a catalyst pad characterized by nanocrystals of a catalyst material effective for growing said at least one semiconducting carbon nanotube, in order to simplify the processing steps of making the device by using conventional growing method of semiconducting carbon nanotube.

Regarding claim 6, prior art's device includes said first end of said at least one semiconducting carbon nanotube incorporates an electrical-conductivity enhancing substance (the electrical-conductivity enhancing substance is the material of said at least one semiconducting carbon nanotube).

Regarding the process limitations recited in claims 5-6, 34, 37 and 46 ("nanocrystals of a catalyst material effective for growing said at least one semiconducting carbon nanotube", and "an electrical-conductivity enhancing substance diffused from said catalyst pad into said first end during growth"), these would not carry patentable weight in this claim drawn to a structure, because distinct structure is not necessarily produced. Note that a "product by process" claim is directed to the product per se, no matter how actually made, In re Hirao, 190 USPQ 15 at 17 (footnote 3). See also In re Brown, 173 USPQ 685; In re Luck, 177 USPQ 523; In re Fessmann, 180 USPQ 324; In re Avery,

186 USPQ 161; In re Wertheim, 191 USPQ 90 (209 USPQ 554 does not deal with this issue); and In re Marosi et al., 218 USPQ 289, all of which make it clear that it is the patentability of the final product per se which must be determined in a "product by process" claim, and not the patentability of the process, and that an old or obvious product produced by a new method is not patentable as a product, whether claimed in "product by process" claims or not. Note that the applicant has the burden of proof in such cases, as the above case law makes clear.

Response to Arguments

Applicant's arguments with respect to claims 1, 3-8, 15-19, 34-35, 37, 43-48 and 52-53 have been considered but are most in view of the new ground(s) of rejection.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ori Nadav whose telephone number is 571-272-1660. The examiner can normally be reached between the hours of 7 AM to 4 PM (Eastern Standard Time) Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Lynne Gurley can be reached on 571-272-4670. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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